

# GP1S01/GP1S01F

High Speed  
Photointerrupter

## ■ Features

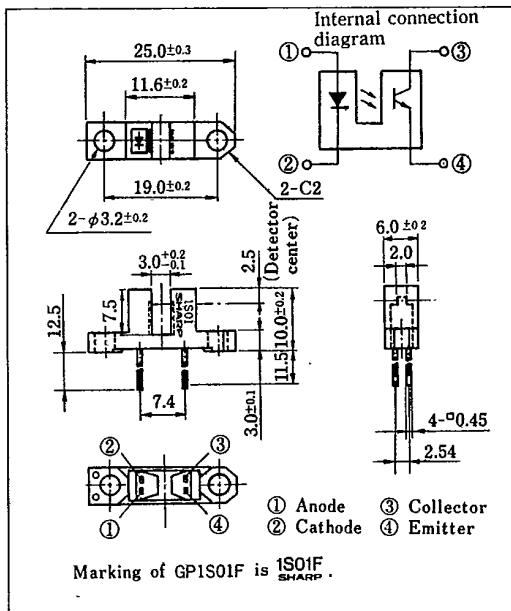
1. High speed response ( $t_r$  : TYP.  $3\mu s$  at  $R_L = 100\Omega$ )
2. High current transfer ratio  
GP1S01 CTR : MIN. 10% } at  $I_F = 20mA$   
GP1S01F CTR : MIN. 8% }
3. Visible light cut-off type : GP1S01F

## ■ Applications

1. Copiers, printers, facsimiles
2. Record players, cassette decks
3. Speed warning device in automobile
4. Optoelectronic switches, optoelectronic counters

## ■ Outline Dimensions

(Unit : mm)



## ■ Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	* <sup>1</sup> Peak forward current	I <sub>FM</sub>	1	A
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	75	mW
Output	Collector-emitter voltage	V <sub>CEO</sub>	35	V
	Emitter-collector voltage	V <sub>ECD</sub>	6	V
	Collector current	I <sub>C</sub>	20	mA
	Collector power dissipation	P <sub>C</sub>	75	mW
Operating temperature		T <sub>opr</sub>	-25 ~ +85	°C
Storage temperature		T <sub>stg</sub>	-40 ~ +100	°C
* <sup>2</sup> Soldering temperature		T <sub>sot</sub>	260	°C

\*1 Pulse width  $\leq 100\mu s$ , Duty ratio = 0.01

\*2 For 5 seconds

## ■ Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20mA	—	1.2	1.4	V
	Peak forward voltage	V <sub>FM</sub>	I <sub>FM</sub> =0.5A	—	3.0	4.0	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> =3V	—	—	10	μA
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =20V	—	10 <sup>-9</sup>	10 <sup>-7</sup>	A
Transfer characteristics	Current transfer ratio	GP1S01	CTR	I <sub>F</sub> =20mA, V <sub>CE</sub> =5V	10	20	150
		GP1S01F			8	20	120
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> =40mA, I <sub>C</sub> =1mA	—	—	0.4	V
	Response time (Rise)	t <sub>r</sub>	I <sub>C</sub> =2mA, V <sub>CE</sub> =2V, R <sub>L</sub> =100Ω	—	—	3	15
	Response time (Fall)	t <sub>f</sub>		—	4	20	μs

Fig. 1 Forward Current vs. Ambient Temperature

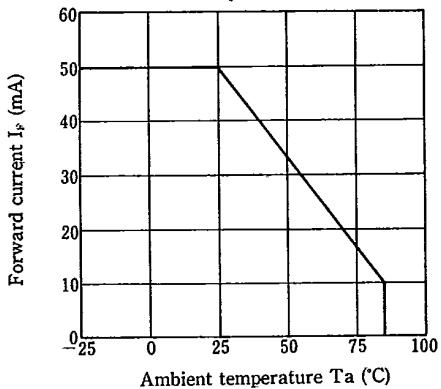


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

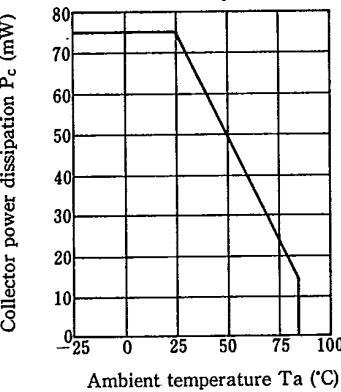


Fig. 3 Peak Forward Current vs. Duty Ratio

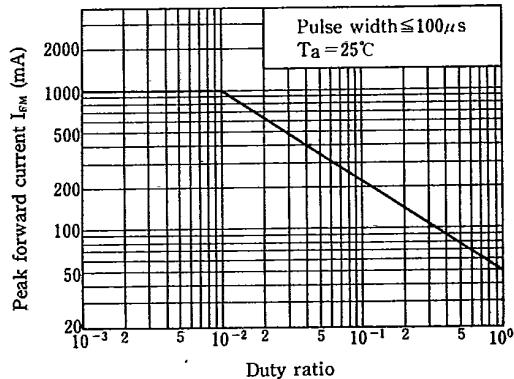
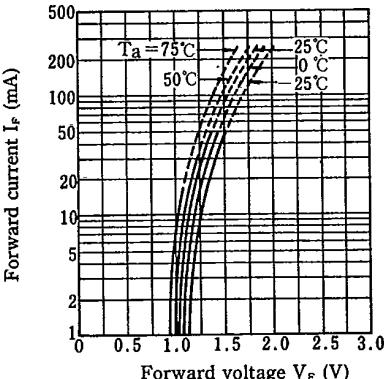
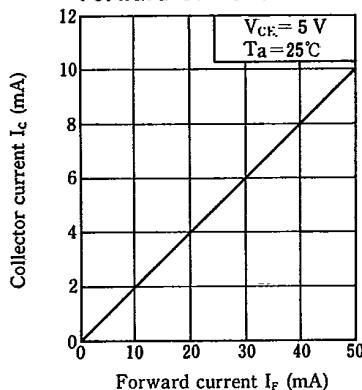


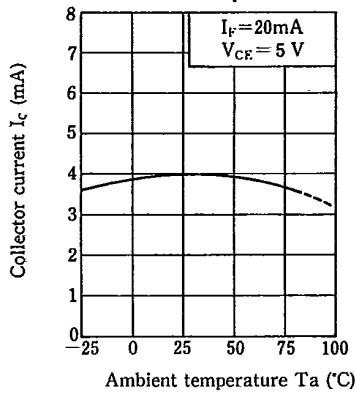
Fig. 4 Forward Current vs. Forward Voltage



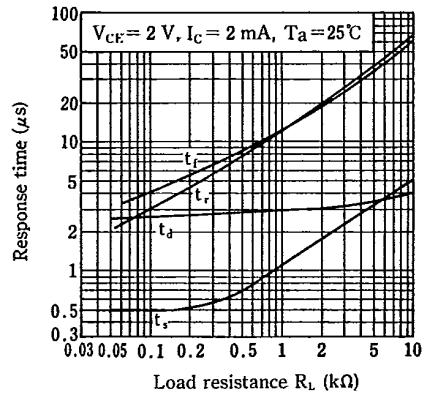
**Fig. 5 Collector Current vs. Forward Current**



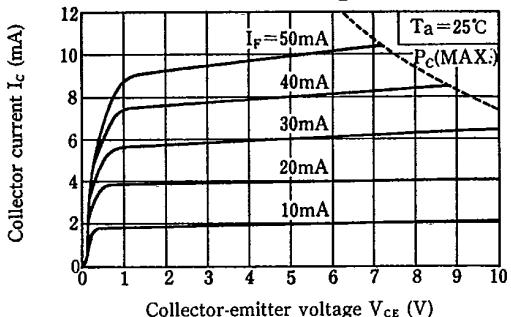
**Fig. 7 Collector Current vs. Ambient Temperature**



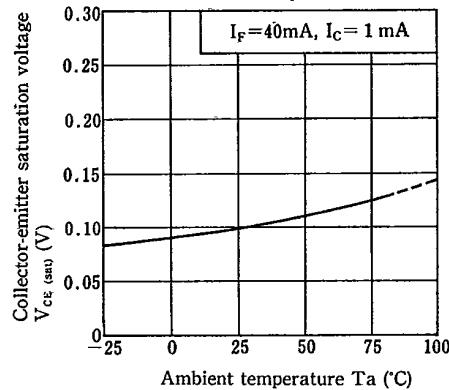
**Fig. 9 Response Time vs. Load Resistance**



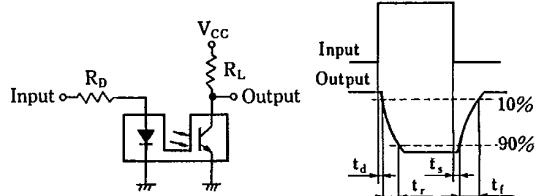
**Fig. 6 Collector Current vs. Collector-emitter Voltage**



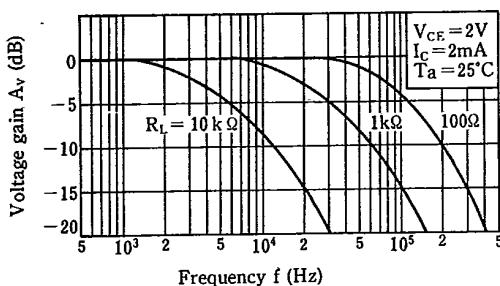
**Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature**



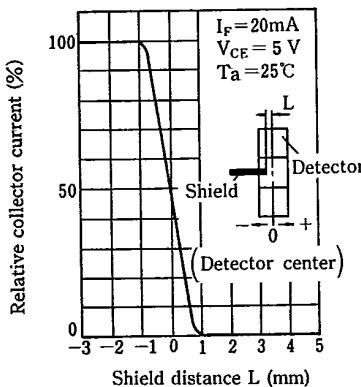
**Test Circuit for Response Time**



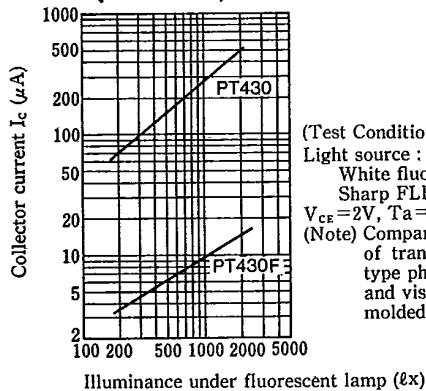
**Fig. 10 Frequency Response**



**Fig. 12 Relative Collector Current vs. Shield Distance (1)**



**Fig. 14 Collector Current vs. Illuminance (Reference)**



(Test Condition)  
 Light source :  
 White fluorescent lamp  
 Sharp FLR-40SW/M  
 $V_{CE} = 2\text{ V}$ ,  $T_a = 25^\circ\text{C}$   
 (Note) Comparison between outputs of transparent resin molded type phototransistor (PT430) and visible light cut-off resin molded type (PT430F)